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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/044,864	10/22/2001	Vladimir Zubkov	01-569/LSI1P177	9835
24319 7.	590 01/13/2006		EXAM	INER
LSI LOGIC CORPORATION			ERDEM, FAZLI	
1621 BARBER LANE				
MS: D-106			ART UNIT	PAPER NUMBER
MILPITAS, C	A 95035		2826	

DATE MAILED: 01/13/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)				
	10/044,864	ZUBKOV ET AL.				
Office Action Summary	Examiner	Art Unit				
	Fazli Erdem	2826				
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the	correspondence address				
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DATE of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  If NO period for reply is specified above, the maximum statutory period value or reply within the set or extended period for reply will, by statute, any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION  36(a). In no event, however, may a reply be to the solution of the	ON. imely filed on the mailing date of this communication. ED (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 01 N	ovember 2005.					
2a) This action is <b>FINAL</b> . 2b) ☑ This	This action is <b>FINAL</b> . 2b)⊠ This action is non-final.					
	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims						
4)⊠ Claim(s) <u>1-3,5-8,10-13 and 15-17</u> is/are pendir	ng in the application.					
4a) Of the above claim(s) is/are withdraw	4a) Of the above claim(s) is/are withdrawn from consideration.					
_	5)⊠ Claim(s) <u>1-3,5-8 and 10-13</u> is/are allowed.					
6)⊠ Claim(s) <u>15-17</u> is/are rejected.						
<u> </u>	7) Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and/o	r election requirement.					
Application Papers						
9)☐ The specification is objected to by the Examine						
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.						
Applicant may not request that any objection to the	- · ·	` '				
Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex						
	ammer. Note the attached Omc	e Action of form PTO-152.				
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).						
a) ☐ All b) ☐ Some * c) ☐ None of:						
1. Certified copies of the priority documents have been received.						
<ul> <li>2. Certified copies of the priority documents have been received in Application No</li> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage</li> </ul>						
application from the International Bureau (PCT Rule 17.2(a)).						
* See the attached detailed Office action for a list of the certified copies not received.						
	·					
Attachment(s)						
1) Notice of References Cited (PTO-892)	y (PTO-413)					
2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)	Pate Patent Application (PTO-152)					
Paper No(s)/Mail Date 6) Other:						

## **DETAILED ACTION**

## Allowable Subject Matter

1. Claims 1-3, 5-8 and 10-13 allowed.

## Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Regarding Claims 15-17, Besser et al. disclose a method of selectively alloying

3. Claims 15-17 rejected under 35 U.S.C. 103(a) as being unpatentable over Besser et al. (6,633,085) in view of Chu et al. (6,881,669) further in view of Lopatin et al. (6,703,307).

interconnect regions by ion implantation where in Fig. 6, surface of silicon oxide layer 34 is implanted/doped by dopants 42 thereby forming a barrier layer, extending from within the silicon dioxide layer to the surface of the silicon oxide layer 34. Claim 9 of Besser et al. disclose that the dopants could be one of Calcium, which is a divalent ion.

Furthermore, consequently, a conductive plug layer 48 is deposited on the surface of the barrier layer, preventing diffusion of copper into the substrate. Following the copper fill process an anneal process is performed. Besser et al. fail to disclose copper layer on the surface of the divalent ionic barrier layer and the required multiple silicon dioxide layers. However, Chu et al. disclose a process for making electronic devices having monolayer diffusion barrier where in paragraph 12 and in claims 1-3 the required copper layer formation method on the surface of divalent ionic barrier layer is disclosed. Furthermore,

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Lopatin et al. disclose a method of implanting after copper seed deposition where in Fig.

3, multiple silicon dioxide layers are disclosed.

It would have been obvious to one of having ordinary skill in the art at the time

the invention was made to include the required copper formation on the surface of the

divalent ionic barrier layer and the required multiple silicon oxide layers in Besser et al.

as taught by Lopatin et al. in order to have a multi-layer semiconductor device.

Conclusion

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Fazli Erdem whose telephone number is (571) 272-1914. The

examiner can normally be reached on M - F 8:00 - 5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Nathan Flynn can be reached on (571) 272-1915. The fax phone number for the

organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published applications

may be obtained from either Private PAIR or Public PAIR. Status information for unpublished

applications is available through Private PAIR only. For more information about the PAIR

system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR

system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

NATHAN J. FLYNN

SUPERVISOR: PATENT EXAMINER

FΕ

January 8, 2006

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